NSN 5961-01-497-8839

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Inclosure Material:
Plastic
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 collector to base voltage/static/emitter open and 12.0 collector-to-emitter, substaining voltage, base open-circuited and 1.5 emitter to
base voltage, static, collector open
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0